

# HEXFRED® Ultrafast Soft Recovery Diode, 90 A



SOT-227

## FEATURES

- Fast recovery time characteristic
- Electrically isolated base plate
- Large creepage distance between terminal
- Simplified mechanical designs, rapid assembly
- Designed and qualified for industrial level
- UL approved file E78996 
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


RoHS  
COMPLIANT

## DESCRIPTION/APPLICATIONS

The dual diode series configuration (VS-HFA90FA120) is used for output rectification or freewheeling/clamping operation and high voltage application.

The semiconductor in the SOT-227 Gen II package is isolated from the copper base plate, allowing for common heatsinks and compact assemblies to be built.

These modules are intended for general applications such as HV power supplies, electronic welders, motor control and inverters.

## PRODUCT SUMMARY

|                                 |               |
|---------------------------------|---------------|
| $V_R$                           | 1200 V        |
| $V_F$ (typical)                 | 2.46 V        |
| $t_{rr}$ (typical)              | 35 ns         |
| $I_{F(AV)}$ per module at $T_C$ | 90 A at 63 °C |
| Package                         | SOT-227       |

## ABSOLUTE MAXIMUM RATINGS

| PARAMETER                                        | SYMBOL         | TEST CONDITIONS                          | MAX.        | UNITS |
|--------------------------------------------------|----------------|------------------------------------------|-------------|-------|
| Cathode to anode breakdown voltage               | $V_R$          |                                          | 1200        | V     |
| Continuous forward current, per leg              | $I_F$          | $T_C = 83\text{ °C}$                     | 45          | A     |
| Single pulse forward current, per leg            | $I_{FSM}$      | $T_J = 25\text{ °C}$                     | 400         |       |
| Maximum power dissipation, per leg               | $P_D$          | $T_C = 83\text{ °C}$                     | 139         | W     |
|                                                  |                | $T_C = 100\text{ °C}$                    | 104         |       |
| RMS isolation voltage                            | $V_{ISOL}$     | Any terminal to case, $t = 1\text{ min}$ | 2500        | V     |
| Operating junction and storage temperature range | $T_J, T_{Stg}$ |                                          | - 55 to 150 | °C    |

## ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)

| PARAMETER                          | SYMBOL   | TEST CONDITIONS                               | MIN. | TYP. | MAX. | UNITS         |
|------------------------------------|----------|-----------------------------------------------|------|------|------|---------------|
| Cathode to anode breakdown voltage | $V_{BR}$ | $I_R = 100\text{ }\mu\text{A}$                | 1200 | -    | -    | V             |
| Forward voltage                    | $V_{FM}$ | $I_F = 25\text{ A}$                           | -    | 2.46 | 3.0  |               |
|                                    |          | $I_F = 40\text{ A}$                           | -    | 2.68 | 3.3  |               |
|                                    |          | $I_F = 25\text{ A}, T_J = 125\text{ °C}$      | -    | 2.22 | -    |               |
|                                    |          | $I_F = 40\text{ A}, T_J = 125\text{ °C}$      | -    | 2.52 | -    |               |
|                                    |          | $I_F = 25\text{ A}, T_J = 150\text{ °C}$      | -    | 2.12 | 2.55 |               |
|                                    |          | $I_F = 40\text{ A}, T_J = 150\text{ °C}$      | -    | 2.43 | 2.96 |               |
| Reverse leakage current            | $I_{RM}$ | $V_R = V_R\text{ rated}$                      | -    | 1.5  | 75   | $\mu\text{A}$ |
|                                    |          | $T_J = 125\text{ °C}, V_R = V_R\text{ rated}$ | -    | 0.5  | 2    | mA            |
|                                    |          | $T_J = 150\text{ °C}, V_R = V_R\text{ rated}$ | -    | 2    | 5    |               |
| Junction capacitance               | $C_T$    | $V_R = 1200\text{ V}$                         | -    | 30   | -    | pF            |

**DYNAMIC RECOVERY CHARACTERISTICS** ( $T_J = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)

| PARAMETER               | SYMBOL    | TEST CONDITIONS                                                                   | MIN. | TYP. | MAX. | UNITS |
|-------------------------|-----------|-----------------------------------------------------------------------------------|------|------|------|-------|
| Reverse recovery time   | $t_{rr}$  | $I_F = 1.0\text{ A}$ , $di_F/dt = 200\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ | -    | 35   | -    | ns    |
|                         |           | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 80   | -    |       |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 130  | -    |       |
| Peak recovery current   | $I_{RRM}$ | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 6.8  | -    | A     |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 11.5 | -    |       |
| Reverse recovery charge | $Q_{rr}$  | $T_J = 25\text{ }^{\circ}\text{C}$                                                | -    | 270  | -    | nC    |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                               | -    | 740  | -    |       |

**THERMAL - MECHANICAL SPECIFICATIONS**

| PARAMETER                               | SYMBOL     | TEST CONDITIONS       | MIN.    | TYP. | MAX. | UNITS                       |
|-----------------------------------------|------------|-----------------------|---------|------|------|-----------------------------|
| Junction to case, single leg conducting | $R_{thJC}$ |                       | -       | -    | 0.48 | $^{\circ}\text{C}/\text{W}$ |
| Junction to case, both legs conducting  |            |                       | -       | -    | 0.24 |                             |
| Case to heatsink                        | $R_{thCS}$ | Flat, greased surface | -       | 0.10 | -    |                             |
| Weight                                  |            |                       | -       | 30   | -    | g                           |
| Mounting torque                         |            |                       | -       | -    | 1.3  | Nm                          |
| Case style                              |            |                       | SOT-227 |      |      |                             |

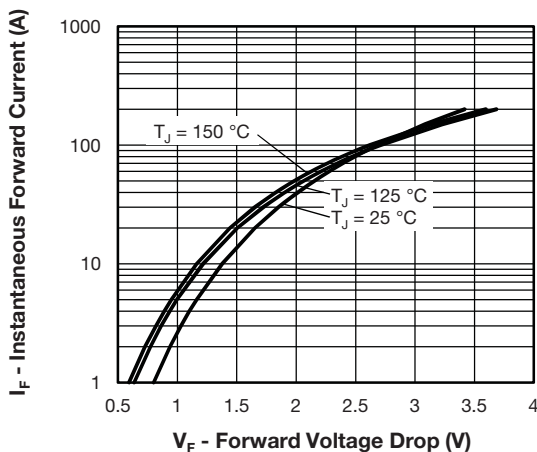


Fig. 1 - Typical Forward Voltage Drop Characteristics (Per Leg)

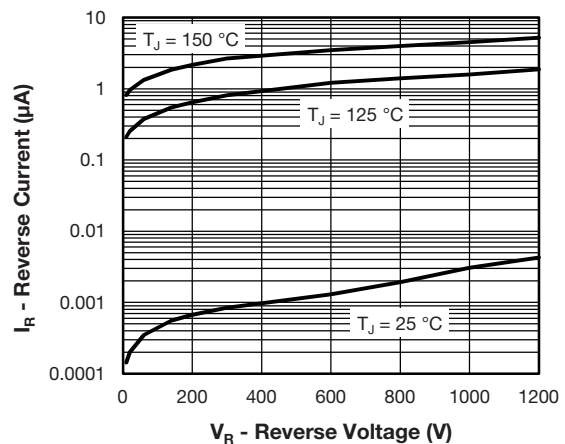


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

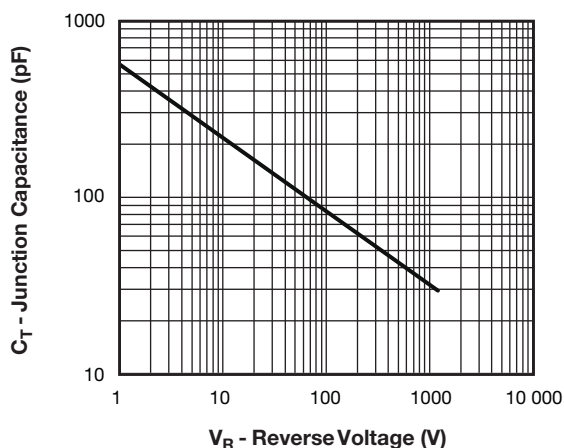


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

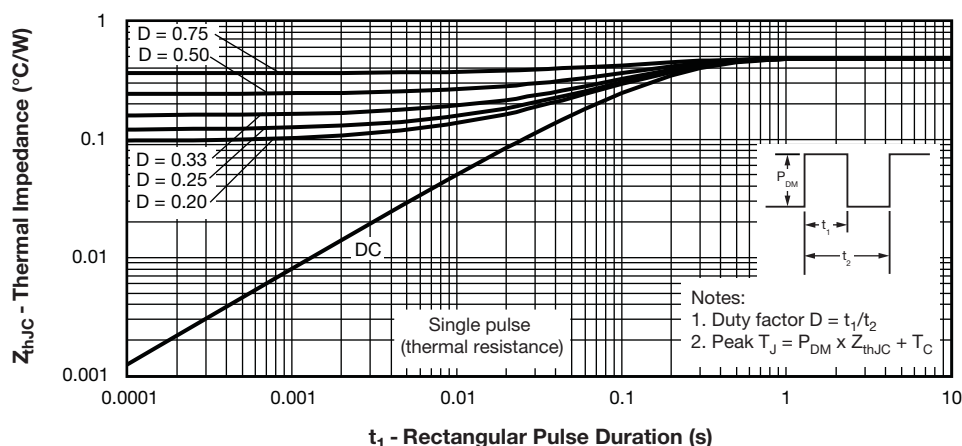
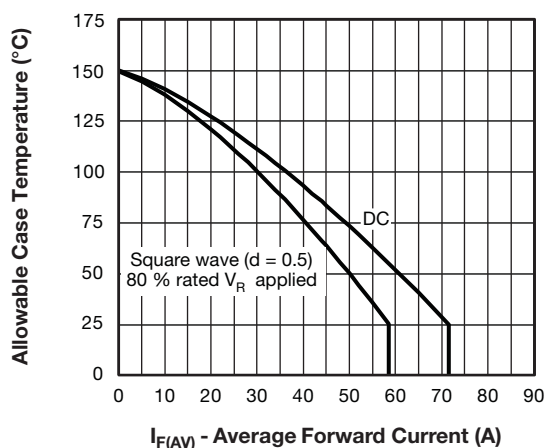

Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics (Per Leg)


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

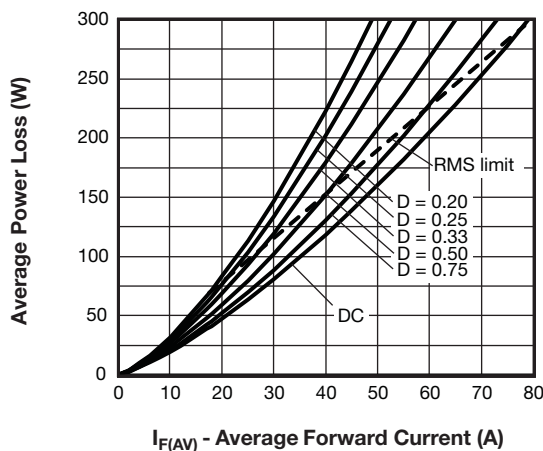


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

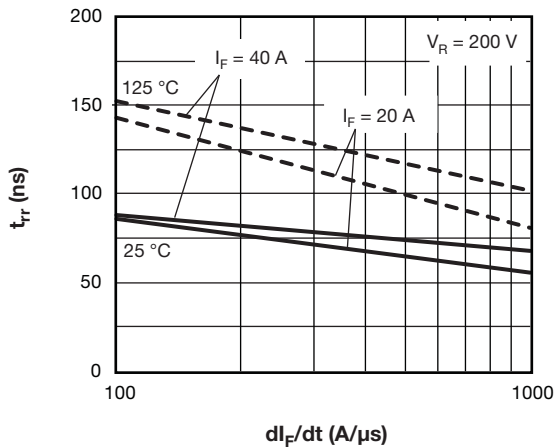
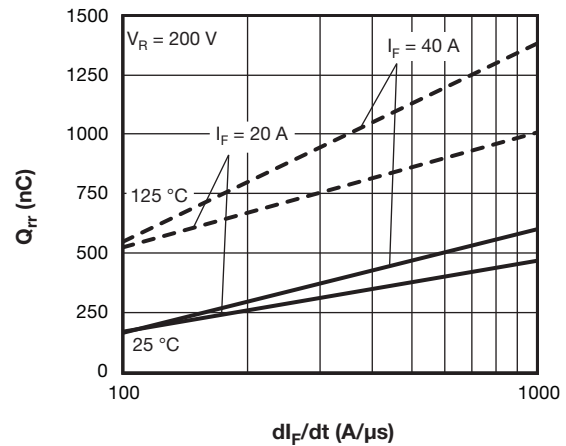
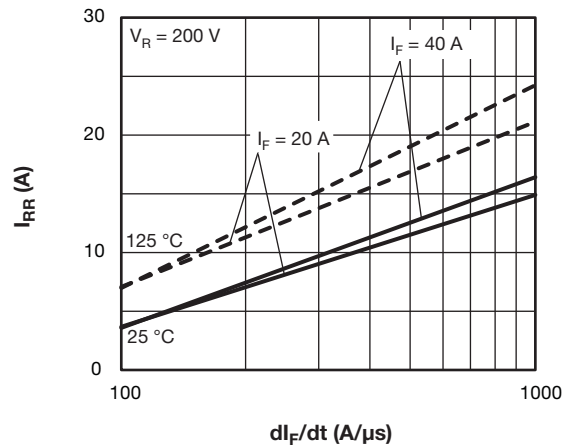
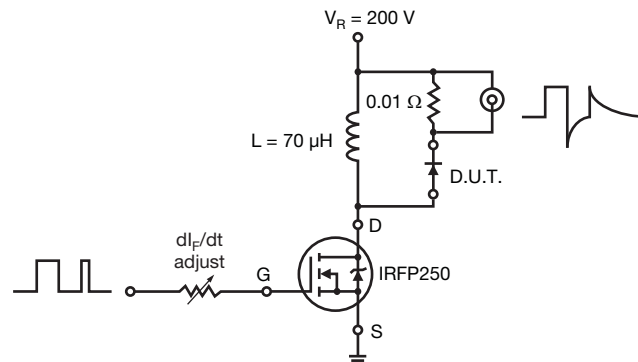

Fig. 7 - Typical Reverse Recovery Time vs.  $dI_F/dt$ 

Fig. 8 - Typical Stored Charge vs.  $dI_F/dt$ 

Fig. 9 - Typical Reverse Recovery Current vs.  $dI_F/dt$ 


Fig. 10 - Reverse Recovery Parameter Test Circuit

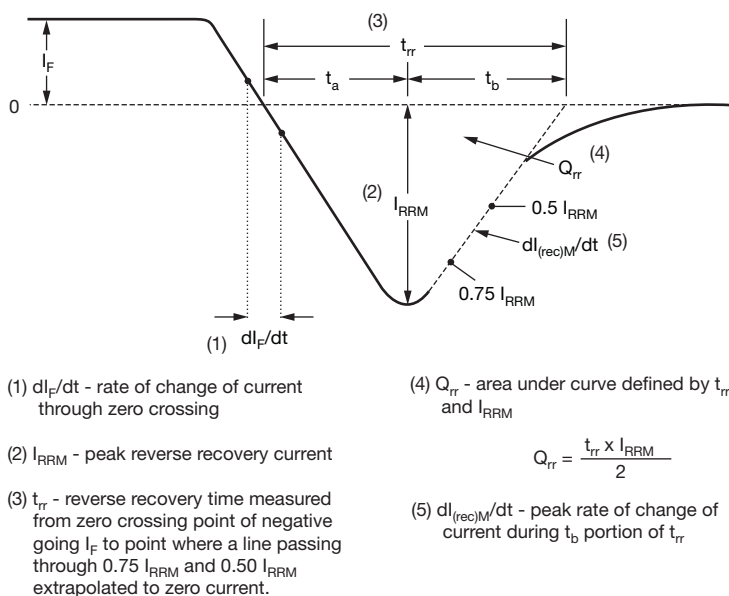
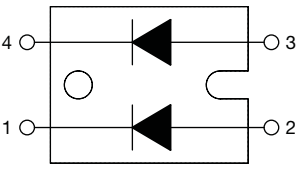


Fig. 11 - Reverse Recovery Waveform and Definitions

## ORDERING INFORMATION TABLE

| Device code | VS-                                                         | HF | A | 90 | F | A | 120 |
|-------------|-------------------------------------------------------------|----|---|----|---|---|-----|
|             | 1                                                           | 2  | 3 | 4  | 5 | 6 | 7   |
| 1           | Vishay Semiconductors product                               |    |   |    |   |   |     |
| 2           | HEXFRED® family                                             |    |   |    |   |   |     |
| 3           | Process designator (A = Electron irradiated)                |    |   |    |   |   |     |
| 4           | Average current (90 = 90 A)                                 |    |   |    |   |   |     |
| 5           | Circuit configuration (2 separate diodes, parallel pin-out) |    |   |    |   |   |     |
| 6           | Package indicator (SOT-227 standard insulated base)         |    |   |    |   |   |     |
| 7           | Voltage rating (120 = 1200 V)                               |    |   |    |   |   |     |

| CIRCUIT CONFIGURATION               |                            |                                                                                                            |
|-------------------------------------|----------------------------|------------------------------------------------------------------------------------------------------------|
| CIRCUIT                             | CIRCUIT CONFIGURATION CODE | CIRCUIT DRAWING                                                                                            |
| 2 separate diodes, parallel pin-out | F                          | <p>Lead Assignment</p>  |



## Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

## Material Category Policy

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.**

**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

**Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.**

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкурентоспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



Тел: +7 (812) 336 43 04 (многоканальный)

Email: [org@lifeelectronics.ru](mailto:org@lifeelectronics.ru)

[www.lifeelectronics.ru](http://www.lifeelectronics.ru)